

TISP8200HDM BUFFERED P-GATE SCR DUAL TISP8201HDM BUFFERED N-GATE SCR DUAL

COMPLEMENTARY BUFFERED-GATE SCRS FOR DUAL POLARITY SLIC OVERVOLTAGE PROTECTION

TISP820xHDM Overvoltage Protectors

High Performance Protection for SLICs with +ve & -ve Battery **Supplies**

TISP8200HDM Negative Overvoltage Protector

- Wide -20 to -110 V Programming Range
- Low +15 mA Max. Gate Triggering Current
- High -150 mA Min. Holding Current

TISP8201HDM Positive Overvoltage Protector

- Wide +20 to +110 V Programming Range
- Low -15 mA Max. Gate Triggering Current
- +20 mA Min. Holding Current

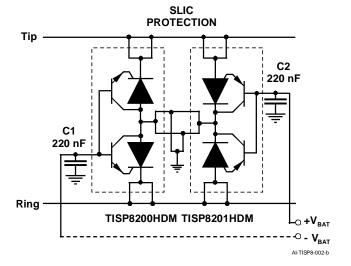
Rated for International Surge Wave Shapes

Wave Shape	Standard	I _{PPSM} A
2/10	GR-1089-CORE	500
10/700	ITU-T K.20/21/45	150
10/1000	GR-1089-CORE	100



.....UL Recognized Component

Circuit Application Diagram





WARNING Cancer and Reproductive Harm

www.P65Warnings.ca.gov

OCTOBER 2005 - REVISED JULY 2019

*RoHS Directive 2015/863, Mar 31, 2015 and Annex. Specifications are subject to change without notice.

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Additional Information

Click these links for more information:











PRODUCT TECHNICAL INVENTORY SAMPLES

CONTACT

Agency Recognition

Description	
UL	File Number: E215609

Description

The TISP8200HDM/TISP8201HDM combination has been designed to protect dual polarity supply rail monolithic SLICs (Subscriber Line Interface Circuits) against overvoltages on the telephone line caused by lightning, a.c. power contact and induction. Protection against negative overvoltages is given by the TISP8200HDM. Protection against positive overvoltages is given by the TISP8201HDM. Both parts are in 8-SOIC (210 mil) surface mount packages.

The TISP8200HDM has an array of two buffered P-gate SCRs with a common anode connection. Each SCR cathode and gate has a separate terminal connection. The NPN buffer transistors reduce the gate supply current. In use, the cathodes of the TISP8200HDM SCRs are connected to the two conductors of the POTS line. The gates are connected to the appropriate negative voltage battery feed of the SLIC driving the line conductor pair, so that the TISP8200HDM protection voltage tracks the SLIC negative supply voltage. The anode of the TISP8200HDM is connected to the SLIC common. Negative overvoltages are initially clipped close to the SLIC negative supply by emitter follower action of the NPN buffer transistor. If sufficient clipping current flows, the SCR will regenerate and switch into a low voltage on-state condition. As the overvoltage subsides the high holding current of the SCR helps prevent d.c. latchup.

The TISP8201HDM has an array of two buffered N-gate SCRs with a common cathode connection. Each SCR anode and gate has a separate terminal connection. The PNP buffer transistors reduce the gate supply current. In use, the anodes of the TISP8201HDM SCRs are connected to the two conductors of the POTS line. The gates are connected to the appropriate positive voltage battery feed of the SLIC driving that line pair, so that the TISP8201HDM protection voltage tracks the SLIC positive supply voltage. The cathode of the TISP8201HDM is connected to the SLIC common. Positive overvoltages are initially clipped close to the SLIC positive supply by emitter follower action of the PNP buffer transistor. If sufficient clipping current flows the SCR will regenerate and switch into a low voltage on-state condition. As the overvoltage subsides the SLIC pulls the conductor voltage down to its normal negative value and this commutates the conducting SCR into a reverse biased condition.

TISP820xHDM Overvoltage Protectors

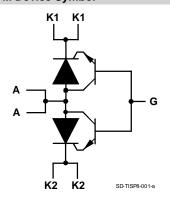
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TISP8200HDM 8-SOIC (210 mil) Package (Top View)

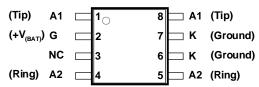
(Tip)	K 1	10	8	<u></u>	(Tip)
(-V _(BAT))	G	2	7	□ A	(Ground)
	NC	3	6	□ A	(Ground)
(Ring)	K2	4	5	<u></u> К2	(Ring)

NC - No internal connection
Terminal typical application names shown in parenthesis
MD-8SOIC(210)-007-a

TISP8200HDM Device Symbol

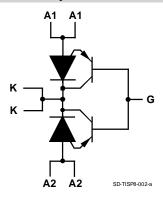


TISP8201HDM 8-SOIC (210 mil) Package (Top View)



NC - No internal connection
Terminal typical application names shown in parenthesis
MD-85GIC[210]-008-a

TISP8201HDM Device Symbol



How to Order

Device	Package	Carrier	Order As	Marking Code	Standard Quantity
TISP8200HDM	8-SOIC (210 mil)	Embossed Tape Reeled	TISP8200HDMR-S	8200H	2000
TISP8201HDM	0-3010 (21011111)	Embossed Tape Reeled	TISP8201HDMR-S	8201H	2000

TISP820xHDM Overvoltage Protectors

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TISP8200HDM Absolute Maximum Ratings, TA = 25 °C (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage, V _{GK} = 0	V _{DRM}	-120	V
Repetitive peak reverse voltage, V _{GA} = -70 V	V _{RRM}	120	
Non-repetitive peak impulse current (see Notes 1, 2 and 3)			
$2/10~\mu s$ (Telcordia GR-1089-CORE, $2/10~\mu s$ voltage wave shape) 5/310 $~\mu s$ (ITU-T K.44, $10/700~\mu s$ voltage wave shape used in K.20/21/45) $10/1000~\mu s$ (Telcordia GR-1089-CORE, $10/1000~\mu s$ voltage wave shape)	I _{PPSM}	-500 -150 -100	A
Non-repetitive peak on-state current, 50/60 Hz (see Notes 1, 2, 3 and 4)			
10 ms 1 s 7 s 900 s	I _{TSM}	60 14 7 3.5	A
Junction temperatur e	TJ	-55 to +150	°C
Storage temperature range	T _{stg}	-65 to +150	°C

- NOTES: 1. Initially the device must be in thermal equilibrium with T_J = 25 °C. The surge may be repeated after the device returns to its initial conditions.
 - 2. These non-repetitive rated currents are peak values. The rated current values may be applied to any cathode-anode ter minal pair.
 - 3. Rated currents only apply if pins 1 & 8 (K1,Tip) are connected together, pins 4 & 5 (K2, Ring) are connected together and pins 6 & 7 (A. Ground) are connected together.
 - 4. These non-repetitive rated terminal currents are for the TISP8200HDM and TISP8201HDM together. Device (A)-terminal positive current values are conducted by the TISP8201HDM and (K)-terminal negative current values by the TISP8200HDM.

TISP8201HDM Absolute Maximum Ratings, T_A = 25 °C (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage, $V_{GA} = 0$	V _{DRM}	120	V
Repetitive peak reverse voltage, V _{GK} = 70 V	V _{RRM}	-120	
Non-repetitive peak impulse current (see Notes 5, 6 and 7)			
$2/10 \mu s$ (Telcordia GR-1089-CORE, $2/10 \mu s$ voltage wave shape)		500	
5/310 μ s (ITU-T K.44, 10/700 μ s voltage wave shape used in K.20/21/45)	I _{PPSM}	150	Α
$10/1000 \mu s$ (Telcordia GR-1089-CORE, $10/1000 \mu s$ voltage wave shape)		100	
Non-repetitive peak on-state current, 50/60 Hz (see Notes 5, 6, 7 and 8)			
10 ms		60	
1s		14	A
7 s	ITSM	7	^
900 s		3.5	
Junction temperatur e	T _J	-55 to +150	°C
Storage temperature range	T _{stg}	-65 to +150	°C

- NOTES: 5. Initially the device must be in thermal equilibrium with T_J = 25 °C. The surge may be repeated after the device returns to its initial conditions.
 - 6. These non-repetitive rated currents are peak values. The rated current values may be applied to any cathode-anode ter minal pair.
 - 7. Rated currents only apply if pins 1 & 8 (A1, Tip) are connected together, pins 4 & 5 (A2, Ring) are connected together and pins 6 & 7 (K, Ground) are connected together.
 - 8. These non-repetitive rated terminal currents are for the TISP8200HDM and TISP8201HDM together. Device (A)-terminal positive current values are conducted by the TISP8201HDM and (K)-terminal negative current values by the TISP8200HDM.

Recommended Operating Conditions

See Figure 3	Min	Тур	Max	Unit	
C1, C2 Gate decoupling capacitor		220		nF]

TISP820xHDM Overvoltage Protectors

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TISP8200HDM Electrical Characteristics, T_A = 25 °C (Unless Otherwise Noted)

	Parameter	Test Conditions		Min	Тур	Max	Unit
I _{DRM}	Repetitive peak off-state current	$V_D = V_{DRM}, V_{GK} = 0$				-5	μΑ
I _{RRM}	Repetitive peak reverse current	$V_R = V_{RRM}, V_{GA} = -70 \text{ V}$				5	μΑ
V _(BO)	Breakover voltage	dv/dt = -250 V/ms, R_{SOURCE} = 300 Ω , V_{GA} = -80 V				-82	V
V _(BO)	Impulse breakover voltage	dv/dt \leq -1000 V/ μ s, Linear voltage ramp, Maximum ramp value = -500 V di/dt = -20 A/ μ s, Linear current ramp, Maximum ramp value = -10 A V _{GA} = -80 V				-90	V
I _H	Holding current	$(I_K)I_T = -1 A$, di/dt = 1 A/ms, $V_{GA} = -80 V$		-150			mA
I _{GT}	Gate trigger current	$(I_K) I_T = -5 \text{ A}, t_{p(g)} \ge 20 \ \mu\text{s}, V_{GA} = -80 \text{ V}$				15	mA
Co	Off-state capacitance	f = 1 MHz, V _d = 1 V rms, Gate open	$V_D = -2 V$			65	pF
	On state supusitance	$V_D = -50 \text{ V}$				30	Pi.

TISP8201HDM Electrical Characteristics, TA = 25 °C (Unless Otherwise Noted)

	Parameter	Test Conditions			Тур	Max	Unit
I _{DRM}	Repetitive peak off-state cur rent	$V_D = V_{DRM}, V_{GA} = 0$				5	μΑ
I _{RRM}	Repetitive peak reverse current	$V_R = V_{RRM}$, $V_{GK} = 70 \text{ V}$				-5	μΑ
V _(BO)	Breakover voltage	$dv/dt = 250 \text{ V/ms}, R_{SOURCE} = 300 \Omega, V_{GK} = 80 \text{ V}$				82	V
V _(BO)	Impulse breakover voltage	dv/dt ≤ 1000 V/µs, Linear voltage ramp, Maximum ramp value = 500 V di/dt = 20 A/µs, Linear current ramp, Maximum ramp value = 10 A V _{GK} = 80 V				90	V
I _H	Holding current	$(I_A) I_T = 1 A$, di/dt = -1 A/ms, $V_{GK} = 80 V$		20			mA
I _{GT}	Gate trigger current	$(I_A) I_T = 5 A, t_{p(g)} \ge 20 \mu s, V_{GK} = 80 V$				-15	mA
Co	Off-state capacitance	f = 1 MHz, V _d = 1 V rms, Gate open	V _D = 2 V			50	pF
			$V_{\rm D} = 50 \text{ V}$			30	

Thermal Characteristics

Parameter		neter	Test Conditions	Min	Тур	Max	Unit
	$R_{\theta JA}$ Junction to amb	ent thermal resistance	EIA/JESD51-7 PCB, EIA/JESD51-2 Environment, P _{TOT} = 4 W (See Note 9)		55		°C/W

9. EIA/JESD51-7 high effective thermal conductivity test board (multi-layer) connected with 0.6 mm printed wiring track widths.

Parameter Measurement Information

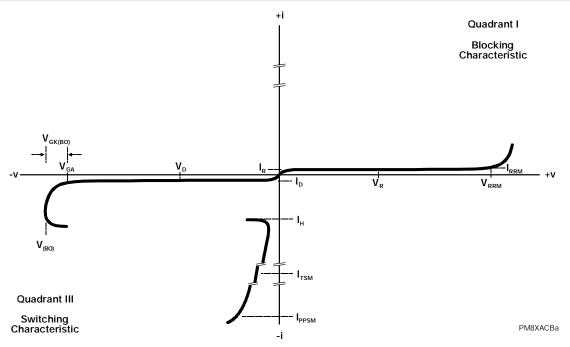


Figure 1. TISP8200HDM KA Terminal Characteristic

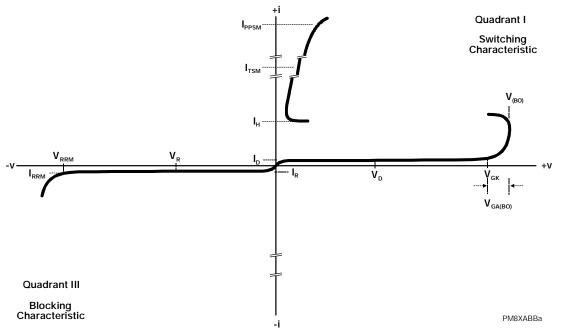


Figure 2. TISP8201HDM AK Terminal Characteristic

AI-TISP8-001-b

Applications Information

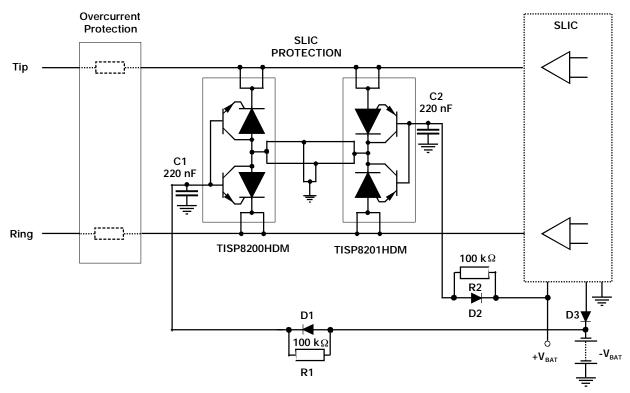


Figure 3. Typical Application Circuit

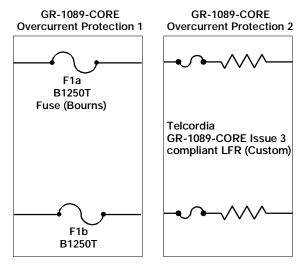


Figure 4. Typical Overcurrent Protection

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